



SamHop Microelectronics Corp.



STS 2307

JUL.30 2004 v1.1

P-Channel Enhancement Mode Field Effect Transistor

| PRODUCT SUMMARY | | |
|------------------|----------------|---|
| V _{DSS} | I _D | R _{DS(ON)} (mΩ) Max |
| -20V | -3A | 80 @ V _{GS} = -4.5V 100 @ V _{GS} = -2.5V |

FEATURES

- Super high dense cell design for low R_{DS(ON)}.
- Rugged and reliable.
- SOT-23 package.



ABSOLUTE MAXIMUM RATINGS (T_A=25 °C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|-----------------------------------|------------|------|
| Drain-Source Voltage | V _{DS} | -20 | V |
| Gate-Source Voltage | V _{GS} | ±12 | V |
| Drain Current-Continuous ^a @ T _J =125°C -Pulsed ^b | I _D | -3 | A |
| | I _{DM} | -11 | A |
| Drain-Source Diode Forward Current ^a | I _S | -1.25 | A |
| Maximum Power Dissipation ^a | P _D | 1.25 | W |
| Operating Junction and Storage Temperature Range | T _J , T _{STG} | -55 to 150 | °C |

THERMAL CHARACTERISTICS

| | | | |
|--|-------------------|-----|------|
| Thermal Resistance, Junction-to-Ambient ^a | R _{thJA} | 100 | °C/W |
|--|-------------------|-----|------|

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ ^c | Max | Unit |
|--|--------------------------|--|------|------------------|------|----------------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{\text{GS}} = 0\text{V}, I_{\text{D}} = -250\mu\text{A}$ | -20 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{\text{DS}} = -16\text{V}, V_{\text{GS}} = 0\text{V}$ | | 1 | | μA |
| Gate-Body Leakage | I_{GSS} | $V_{\text{GS}} = \pm 10\text{V}, V_{\text{DS}} = 0\text{V}$ | | ± 100 | | nA |
| ON CHARACTERISTICS ^b | | | | | | |
| Gate Threshold Voltage | $V_{\text{GS(th)}}$ | $V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250\mu\text{A}$ | -0.5 | -0.8 | -1.5 | V |
| Drain-Source On-State Resistance | $R_{\text{DS(ON)}}$ | $V_{\text{GS}} = -4.5\text{V}, I_{\text{D}} = -4.0\text{A}$ | | 70 | 80 | m-ohm |
| | | $V_{\text{GS}} = -2.5\text{V}, I_{\text{D}} = -2.0\text{A}$ | | 85 | 100 | m-ohm |
| On-State Drain Current | $I_{\text{D(ON)}}$ | $V_{\text{DS}} = -5\text{V}, V_{\text{GS}} = -4.5\text{V}$ | -15 | | | A |
| Forward Transconductance | g_{FS} | $V_{\text{DS}} = -5\text{V}, I_{\text{D}} = -5\text{A}$ | 4 | | | S |
| DYNAMIC CHARACTERISTICS ^c | | | | | | |
| Input Capacitance | C_{ISS} | $V_{\text{DS}} = -15\text{V}, V_{\text{GS}} = 0\text{V}$ $f = 1.0\text{MHz}$ | | 586 | | pF |
| Output Capacitance | C_{OSS} | | | 101 | | pF |
| Reverse Transfer Capacitance | C_{RSS} | | | 59 | | pF |
| SWITCHING CHARACTERISTICS ^c | | | | | | |
| Turn-On Delay Time | $t_{\text{D(ON)}}$ | $V_{\text{DD}} = -10\text{V},$ $I_{\text{D}} = -1\text{A},$ $V_{\text{GS}} = -4.5\text{V},$ $R_{\text{L}} = 10 \text{ ohm}$ $R_{\text{GEN}} = 6 \text{ ohm}$ | | 6.5 | | ns |
| Rise Time | t_{r} | | | 32.1 | | ns |
| Turn-Off Delay Time | $t_{\text{D(OFF)}}$ | | | 58.4 | | ns |
| Fall Time | t_{f} | | | 48 | | ns |
| Total Gate Charge | Q_{g} | $V_{\text{DS}} = -10\text{V}, I_{\text{D}} = -3\text{A},$ $V_{\text{GS}} = -4.5\text{V}$ | | 5.92 | | nC |
| Gate-Source Charge | Q_{gs} | | | 1.36 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 1.4 | | nC |

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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ ^c | Max | Unit |
|---|----------|-----------------------------|-----|------------------|------|------|
| DRAIN-SOURCE DIODE CHARACTERISTICS ^b | | | | | | |
| Diode Forward Voltage | V_{SD} | $V_{GS} = 0V, I_S = -1.25A$ | | -0.815 | -1.2 | V |

Notes

- a. Surface Mounted on FR4 Board, $t \leq 10\text{sec}$.
- b. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
- c. Guaranteed by design, not subject to production testing.

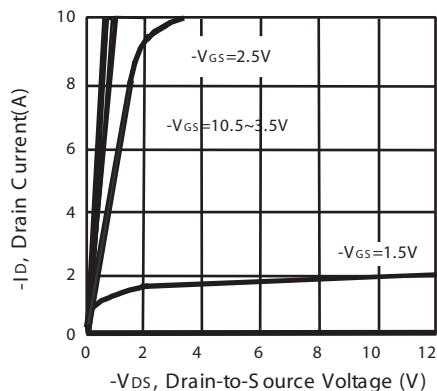


Figure 1. Output Characteristics

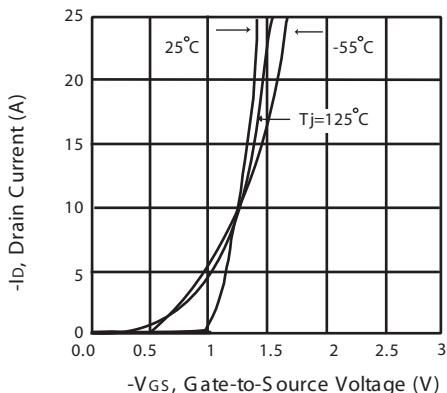


Figure 2. Transfer Characteristics

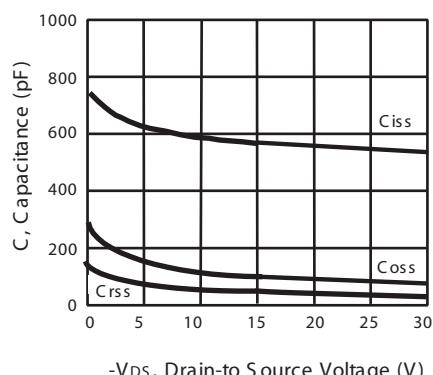


Figure 3. Capacitance

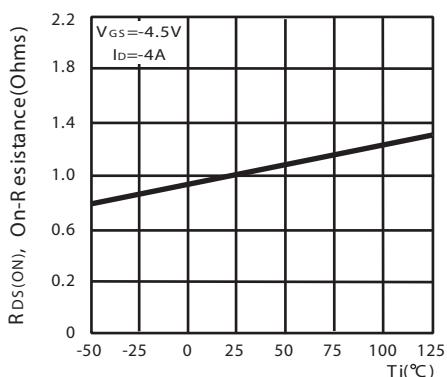
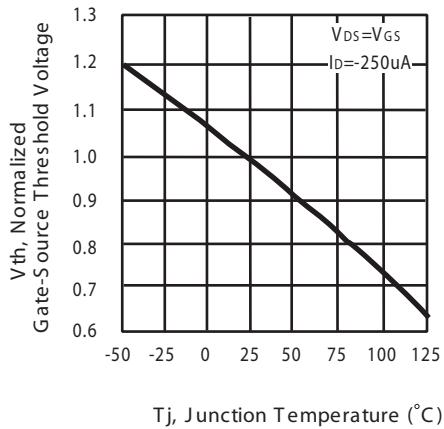


Figure 4. On-Resistance Variation with Temperature

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with Temperature

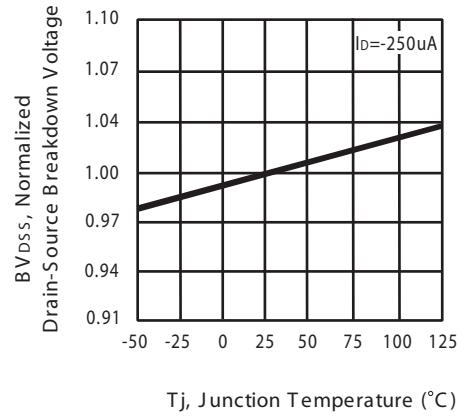


Figure 6. Breakdown Voltage Variation with Temperature

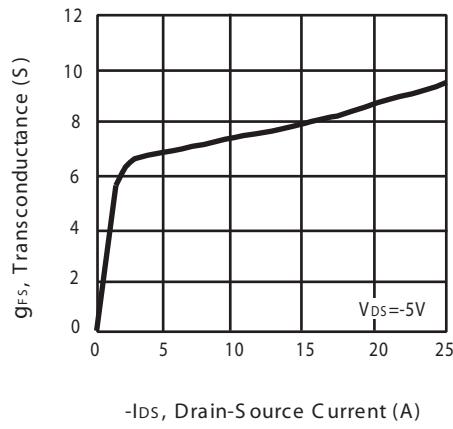


Figure 7. Transconductance Variation with Drain Current

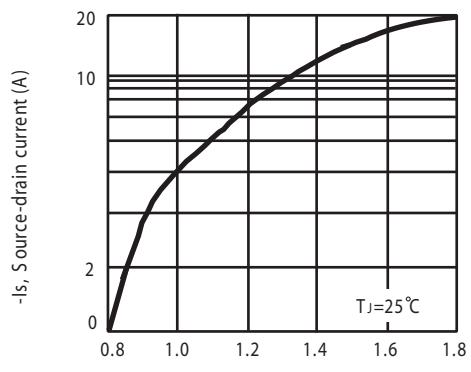


Figure 8. Body Diode Forward Voltage Variation with Source Current

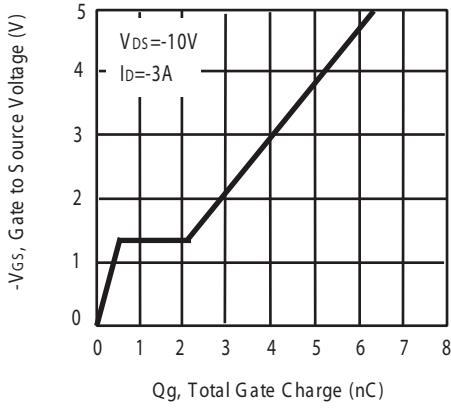


Figure 9. Gate Charge

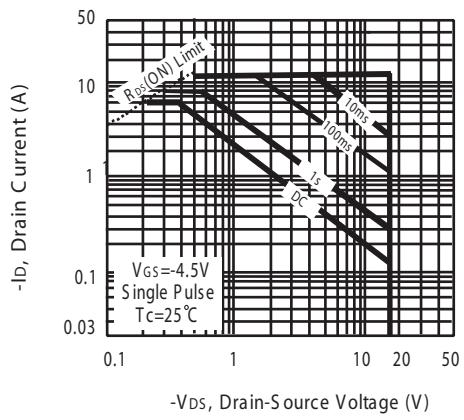
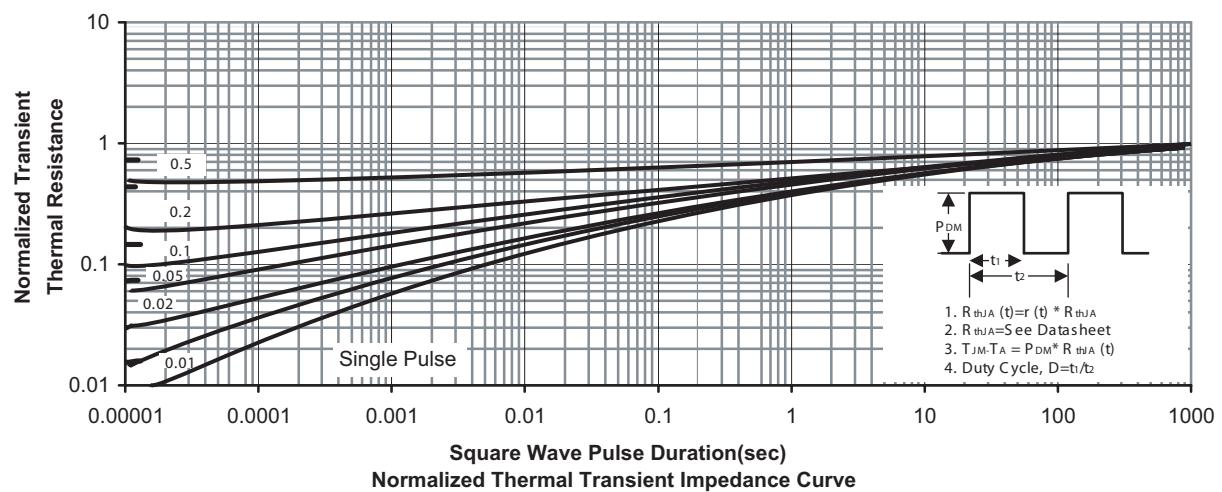
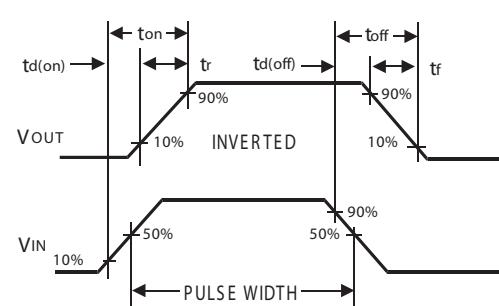
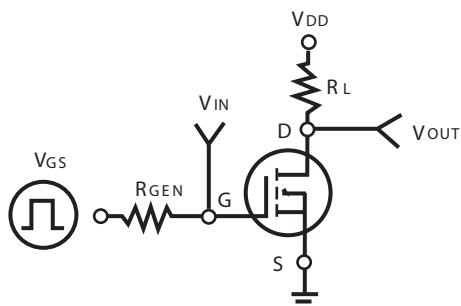


Figure 10. Maximum Safe Operating Area

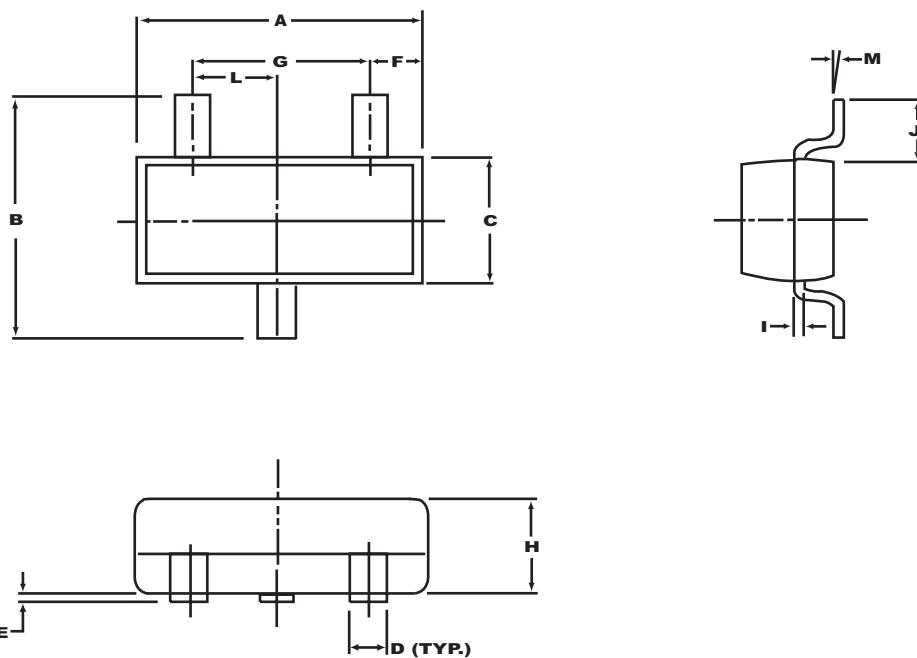
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PACKAGE OUTLINE DIMENSIONS

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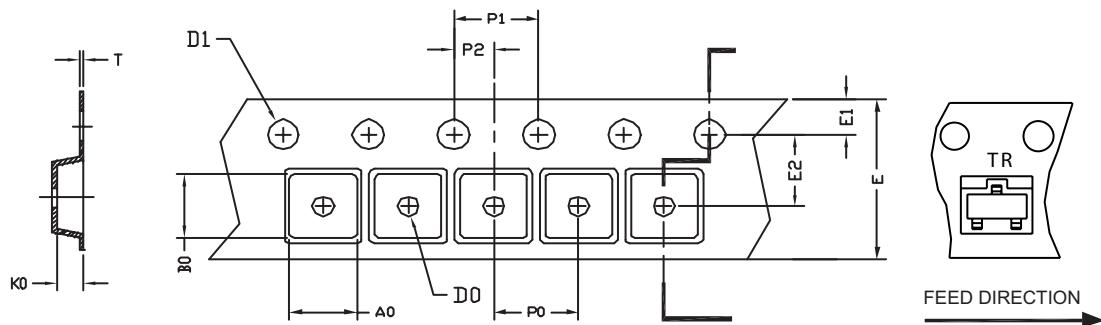


| SYMBOLS | MILLIMETERS | | INCHES | |
|---------|-------------|------|------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 2.70 | 3.10 | 0.106 | 0.122 |
| B | 2.40 | 2.80 | 0.094 | 0.110 |
| C | 1.40 | 1.60 | 0.055 | 0.063 |
| D | 0.35 | 0.50 | 0.014 | 0.020 |
| E | 0 | 0.10 | 0 | 0.004 |
| F | 0.45 | 0.55 | 0.018 | 0.022 |
| G | 1.90 REF. | | 0.075 REF. | |
| H | 1.00 | 1.30 | 0.039 | 0.051 |
| I | 0.10 | 0.20 | 0.004 | 0.008 |
| J | 0.40 | - | 0.016 | - |
| L | 0.45 | 1.15 | 0.033 | 0.045 |
| M | 0° | 10° | 0° | 10° |

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SOT-23 Tape and Reel Data

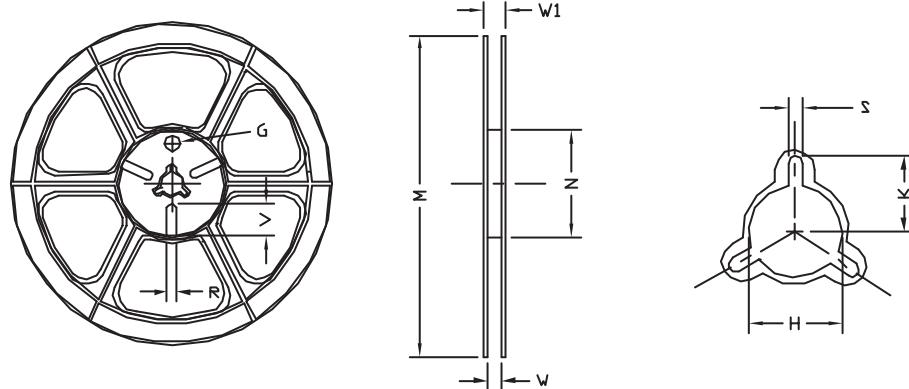
SOT-23 Carrier Tape



UNIT:mm

| PACKAGE | A_0 | B_0 | K_0 | D_0 | D_1 | E | E_1 | E_2 | P_0 | P_1 | P_2 | T |
|---------|--------------------|--------------------|--------------------|-------------------------------|-------------------------------|----------------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| SOT-23 | 3.20 ± 0.10 | 3.00 ± 0.10 | 1.33 ± 0.10 | $\frac{1}{2}$ 1.00 $+0.25$ | $\frac{1}{2}$ 1.50 $+0.10$ | 8.00 $+0.30$ -0.10 | 1.75 ± 0.10 | 3.50 ± 0.05 | 4.00 ± 0.10 | 4.00 ± 0.10 | 2.00 ± 0.05 | 0.20 ± 0.02 |

SOT-23 Reel



UNIT:mm

| TAPE SIZE | REEL SIZE | M | N | W | W_1 | H | K | S | G | R | V |
|-----------|-------------------|------------------------------|-----------------------------|-------------------|--------------------|---------------------------------|------|-------------------|--------------------|------|-------|
| 8mm | $\frac{1}{2}$ 178 | $\frac{1}{2}$ 178 ± 1 | $\frac{1}{2}$ 60 ± 1 | 9.00 ± 0.5 | 12.00 ± 0.5 | $\frac{1}{2}$ 13.5 ± 0.5 | 10.5 | 2.00 ± 0.5 | $\frac{1}{2}$ 10.0 | 5.00 | 18.00 |